

Analog Peripherals

- **8-Bit ADC**
 - Up to 500 ksp/s
 - Up to 8 external inputs
 - Programmable amplifier gains of 4, 2, 1, & 0.5
 - VREF from external pin or V_{DD}
 - Built-in temperature sensor
 - External conversion start input
- **Comparator**
 - Programmable hysteresis and response time
 - Configurable as interrupt or reset source
 - Low current (<0.5 μ A)

On-chip Debug

- On-chip debug circuitry facilitates full speed, non-intrusive in-system debug (no emulator required)
- Provides breakpoints, single stepping, inspect/modify memory and registers
- Superior performance to emulation systems using ICE-chips, target pods, and sockets

Supply Voltage 2.7 to 3.6 V

- Typical operating current: 6.6 mA @ 25 MHz;
14 μ A @ 32 kHz
- Typical stop mode current: 0.1 μ A
- Temperature range: -40 to +85 °C

Full Technical Data Sheet

- C8051F300/1/2/3/4/5

High Speed 8051 μ C Core

- Pipelined instruction architecture; executes 70% of instructions in 1 or 2 system clocks
- Up to 25 MIPS throughput with 25 MHz clock
- Expanded interrupt handler

Memory

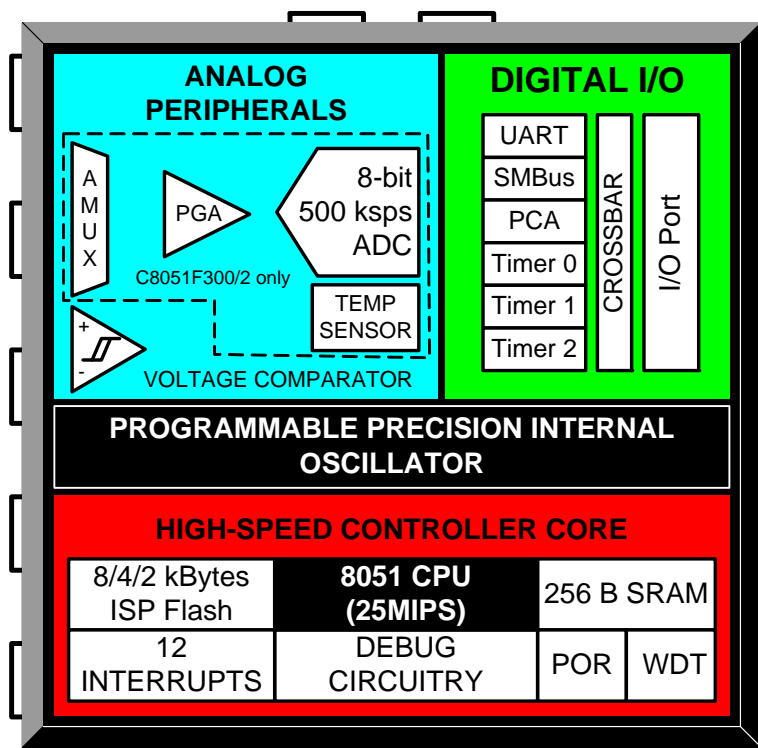
- 256 bytes internal data RAM
- 8 kB Flash; 512 bytes are reserved in the 8 kB devices

Digital Peripherals

- 8 Port I/O; All 5 V tolerant with high sink current
- Hardware enhanced UART and SMBus™ serial ports
- Three general-purpose 16-bit counter/timers
- 16-bit programmable counter array (PCA) with three capture/compare modules
- Real time clock mode using PCA or timer and external clock source

Clock Sources

- Internal oscillator: 24.5 MHz with \pm 2% accuracy supports UART operation
- External oscillator: Crystal, RC, C, or clock (1 or 2 pin modes)
- Can switch between clock sources on-the-fly; Useful in power saving modes



C8051F300-GDI

1. Ordering Information

Table 1.1. Product Selection Guide

Ordering Part Number	MIPS (Peak)	Flash Memory (kB)*	RAM (Bytes)	SMBus/I ² C	UART	Timers (16-bit)	Programmable Counter Array	Digital Port I/Os	8-bit 500 ksps ADC	Programmable Current Reference	Temperature Sensor	Analog Comparators	Lead-free (RoHS Compliant)	Package
C8051F300-GDI	25	8	256	1	1	3	✓	8	✓	✓	✓	1	✓	Tested Die in Wafer Form
*Note: 512 bytes reserved for factory use.														

2. Pin Definitions

Table 2.1. Pin Definitions for the C8051F300-GDI

Name	Physical Pad Number	Type	Description
VREF / P0.0	3	A In D I/O or A In	External Voltage Reference Input. Port 0.0.
P0.1	4	D I/O or A In	Port 0.1.
V _{DD}	5		Power Supply Voltage.
XTAL1 / P0.2	6	A In D I/O or A In	Crystal Input. This pin is the external oscillator circuit return for a crystal or ceramic resonator. Port 0.2.
XTAL2 / P0.3	7	A Out D I/O	Crystal Input/Output. For an external crystal or resonator, this pin is the excitation driver. This pin is the external clock input for CMOS, capacitor, or RC network configurations. Port 0.3.
P0.4	13	D I/O or A In	Port 0.4.
P0.5	14	D I/O or A In	Port 0.5.
C2CK / RST	15	D I/O D I/O	Clock signal for the C2 Development Interface. Device Reset. Open-drain output of internal POR or V _{DD} monitor. An external source can initiate a system reset by driving this pin low for at least 10 μ s.
P0.6 / CNVSTR	16	D I/O or A In D I/O	Port 0.6. ADC External Convert Start Input Strobe.
C2D / P0.7	17	D I/O D I/O or A In	Data signal for the C2 Development Interface. Port 0.7.
GND	18		Ground.

C8051F300-GDI

3. Bonding Instructions

Table 3.1. C8051F300-GDI Pad Connections

Physical Pad Number	Example Package Pin Number (11-QFN)	Package Pin Name	Physical Pad X (μm)	Physical Pad Y (μm)
1	Reserved*		–1001.5	–575
2	Reserved*		–926.5	–575
3	1	VREF/P0.0	–795.5	–575
4	2	P0.1	–615.5	–575
5	3	VDD	346.17	–575
6	4	XTAL1/P0.2	615.5	–575
7	5	XTAL2/P0.3	795.5	–575
8	Reserved*		926.5	–575
9	Reserved*		1001.5	–575
10	Reserved*		1000	–429.57
11	Reserved*		1001.5	575
12	Reserved*		926.5	575
13	6	P0.4	790.5	575
14	7	P0.5	620.5	575
15	8	/RST/C2CK	440.5	575
16	9	P0.6/CNVSTR	–523.5	575
17	10	C2D/P0.7	–703.5	575
18	11	GND	–834.5	575
19	Reserved*		–926.5	575
20	Reserved*		–1001.5	575

***Note:** Pins marked “Reserved” should not be connected.

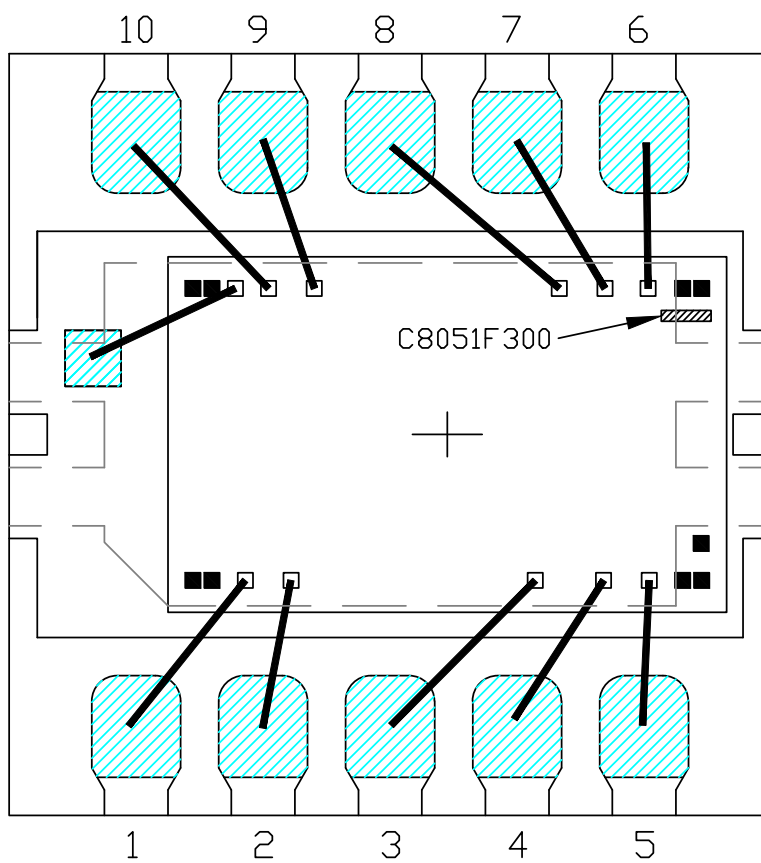


Figure 3.1. Example Die Bonding (QFN-11)

C8051F300-GDI

Table 3.2. Wafer and Die Information

Wafer ID	C8051F300
Wafer Dimensions	8 in
Die Dimensions	1.40 mm x 2.2 mm
Wafer Thickness	12 mil \pm 1 mil
Wafer Identification	Notch
Scribe Line Width	80 μ m
Die Per Wafer*	Contact Sales for info
Passivation	Standard
Wafer Packaging Detail	Wafer Jar
Bond Pad Dimensions	60 μ m x 60 μ m
Maximum Processing Temperature	250 °C
Electronic Die Map Format	.txt
Bond Pad Pitch Minimum	75 μ m
*Note: This is the Expected Known Good Die yielded per wafer and represents the batch order quantity (one wafer).	

4. Wafer Storage Guidelines

It is necessary to conform to appropriate wafer storage practices to avoid product degradation or contamination.

- Wafers may be stored for up to 18 months in the original packaging supplied by Silicon Labs.
- Wafers must be stored at a temperature of 18–24 °C.
- Wafers must be stored in a humidity-controlled environment with a relative humidity of <30%.
- Wafers should be stored in a clean, dry, inert atmosphere (e.g. nitrogen or clean, dry air).

C8051F300-GDI

DOCUMENT CHANGE LIST

Revision 1.0 to Revision 1.1

- Changed Wafer Packaging Detail to “Wafer Jar” in Table 3.2 on page 6.

NOTES:

C8051F300-GDI

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